

TEMIC

Siliconix

SUP/SUB65P06-20

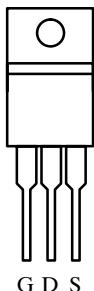
P-Channel Enhancement-Mode Transistors

175°C Maximum Junction Temperature

Product Summary

$V_{(BR)DSS}$ (V)	$r_{DS(on)}$ (Ω)	I_D (A)
-60	0.020	-65 ^a

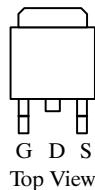
TO-220AB



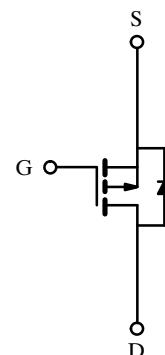
Top View

SUP65P06-20

TO-263



SUB65P06-20



P-Channel MOSFET

Absolute Maximum Ratings ($T_C = 25^\circ\text{C}$ Unless Otherwise Noted)

Parameter		Symbol	Limit	Unit
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current ($T_J = 175^\circ\text{C}$)	$T_C = 25^\circ\text{C}$	I_D	-65 ^a	A
	$T_C = 125^\circ\text{C}$		-39	
Pulsed Drain Current		I_{DM}	-200	
Avalanche Current		I_{AR}	-60	
Repetitive Avalanche Energy ^b	$L = 0.1 \text{ mH}$	E_{AR}	180	mJ
Power Dissipation	$T_C = 25^\circ\text{C}$ (TO-220AB and TO-263)	P_D	187 ^d	W
	$T_A = 125^\circ\text{C}$ (TO-263) ^c		3.7	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 175	°C

Thermal Resistance Ratings

Parameter		Symbol	Limit	Unit
Junction-to-Ambient	PCB Mount (TO-263) ^c	R_{thJA}	40	°C/W
	Free Air (TO-220AB)	R_{thJA}	62.5	
Junction-to-Case		R_{thJC}	0.8	

Notes:

- a. Package limited.
- b. Duty cycle $\leq 1\%$.
- c. When mounted on 1" square PCB (FR-4 material).
- d. See SOA curve for voltage derating.

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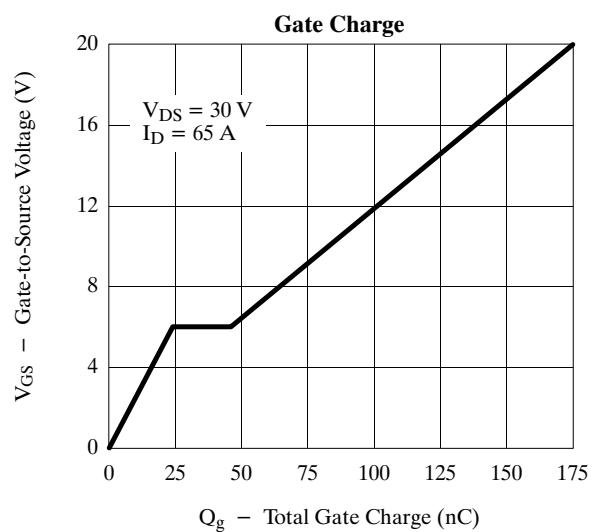
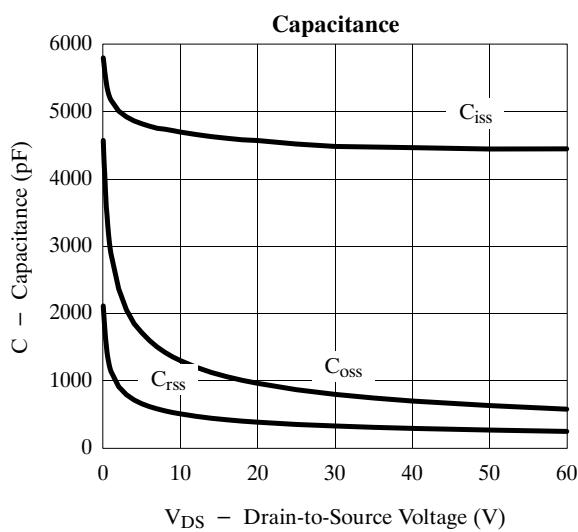
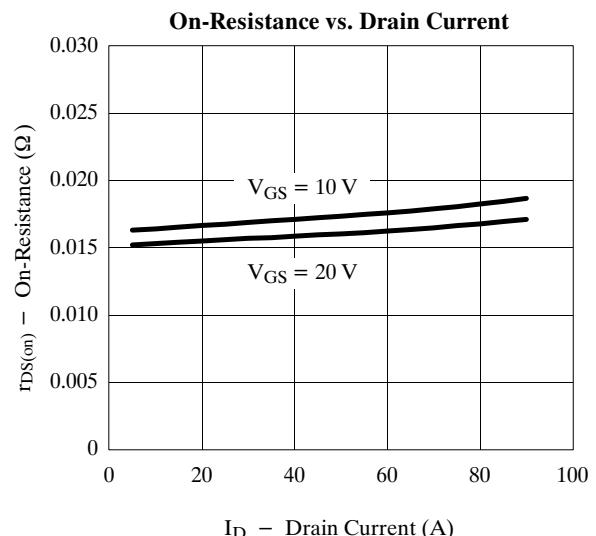
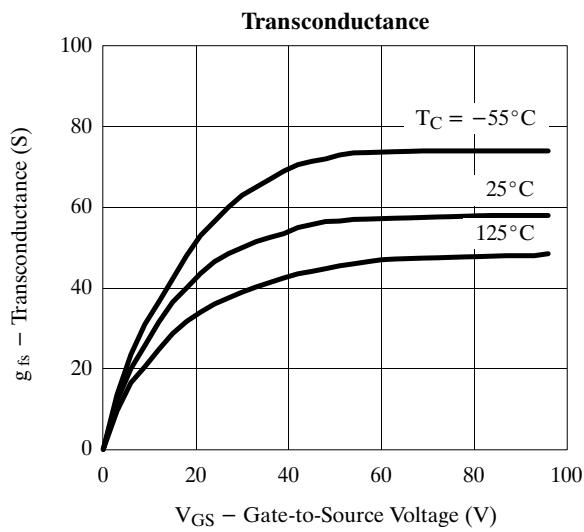
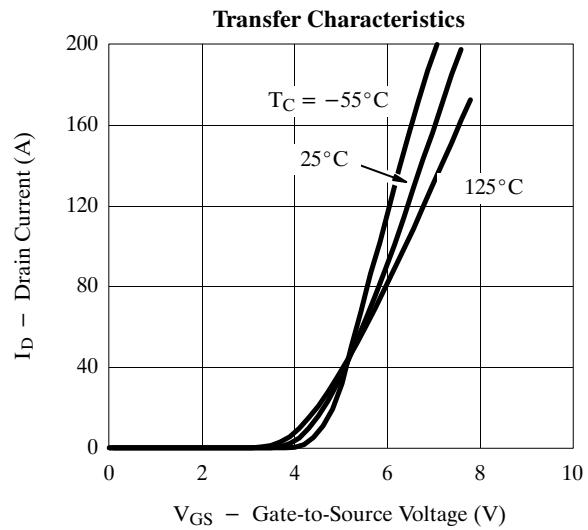
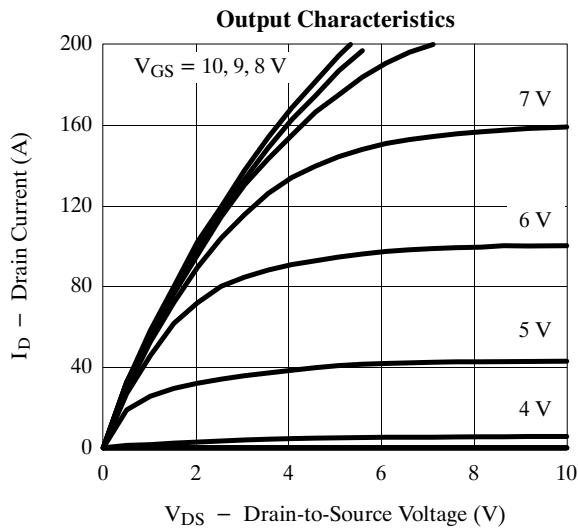
Specifications ($T_J = 25^\circ\text{C}$ Unless Otherwise Noted)

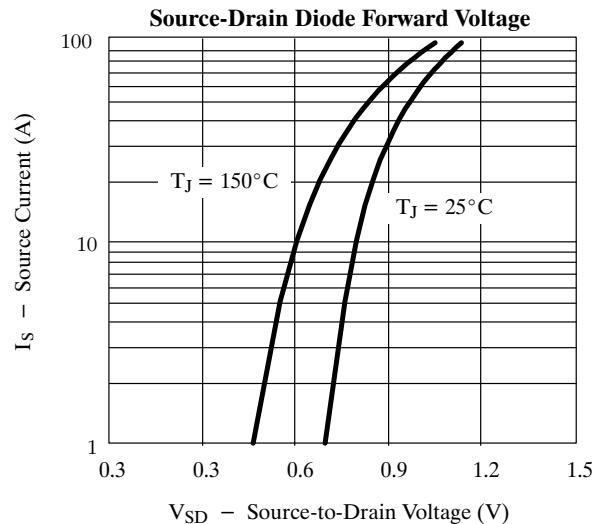
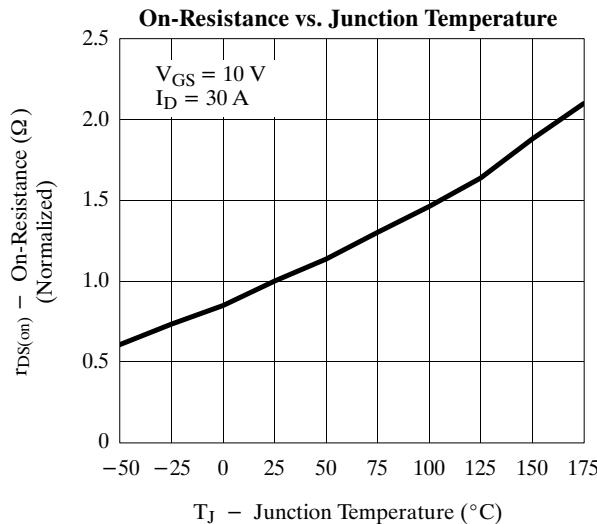
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-60			V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = -250 \mu\text{A}$	-2.0	-3.0	-4.0	
Gate-Body Leakage	I_{GSS}	$V_{\text{DS}} = 0 \text{ V}, V_{\text{GS}} = \pm 20 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}} = -60 \text{ V}, V_{\text{GS}} = 0 \text{ V}$			-1	μA
		$V_{\text{DS}} = -60 \text{ V}, V_{\text{GS}} = 0 \text{ V}, T_J = 125^\circ\text{C}$			-50	
		$V_{\text{DS}} = -60 \text{ V}, V_{\text{GS}} = 0 \text{ V}, T_J = 175^\circ\text{C}$			-150	
On-State Drain Current ^{bb}	$I_{\text{D}(\text{on})}$	$V_{\text{DS}} = -5 \text{ V}, V_{\text{GS}} = -10 \text{ V}$	-120			A
Drain-Source On-State Resistance ^b	$r_{\text{DS}(\text{on})}$	$V_{\text{GS}} = -10 \text{ V}, I_D = -30 \text{ A}$		0.017	0.020	Ω
		$V_{\text{GS}} = -10 \text{ V}, I_D = -30 \text{ A}, T_J = 125^\circ\text{C}$			0.033	
		$V_{\text{GS}} = -10 \text{ V}, I_D = -30 \text{ A}, T_J = 175^\circ\text{C}$			0.042	
Forward Transconductance ^b	g_{fs}	$V_{\text{DS}} = -15 \text{ V}, I_D = -30 \text{ A}$	25			S
Dynamic^a						
Input Capacitance	C_{iss}	$V_{\text{GS}} = 0 \text{ V}, V_{\text{DS}} = -25 \text{ V}, f = 1 \text{ MHz}$		4500		pF
Output Capacitance	C_{oss}			870		
Reversen Transfer Capacitance	C_{rss}			350		
Total Gate Charge ^c	Q_g	$V_{\text{DS}} = -30 \text{ V}, V_{\text{GS}} = -10 \text{ V}, I_D = -65 \text{ A}$		85	120	nC
Gate-Source Charge ^c	Q_{gs}			24		
Gate-Drain Charge ^c	Q_{gd}			22		
Turn-On Delay Time ^c	$t_{\text{d}(\text{on})}$	$V_{\text{DD}} = -30 \text{ V}, R_L = 0.47 \Omega$ $I_D = -65 \text{ A}, V_{\text{GEN}} = -10 \text{ V}, R_G = 2.5 \Omega$		15	40	ns
Rise Time ^c	t_r			40	80	
Turn-Off Delay Time ^c	$t_{\text{d}(\text{off})}$			65	120	
Fall Time ^c	t_f			30	60	
Source-Drain Diode Ratings and Characteristics ($T_C = 25^\circ\text{C}$)^a						
Continuous Current	I_s				-65	A
Pulsed Current	I_{SM}				-200	
Forward Voltage ^b	V_{SD}	$I_F = -65 \text{ A}, V_{\text{GS}} = 0 \text{ V}$		-1.1	-1.4	V
Reverse Recovery Time	t_{rr}	$I_F = -65 \text{ A}, \text{di}/\text{dt} = 100 \text{ A}/\mu\text{s}$		70	120	ns
Peak Reverse Recovery Current	$I_{\text{RM}(\text{REC})}$			7	9	A
Reverse Recovery Charge	Q_{rr}			0.245	0.54	μC

Notes:

- a. Guaranteed by design, not subject to production testing.
- b. Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$.
- c. Independent of operating temperature.

Typical Characteristics (25°C Unless Noted)



SUP/SUB65P06-20**Typical Characteristics (25°C Unless Otherwise Noted)****Thermal Ratings**